www.vishay.com

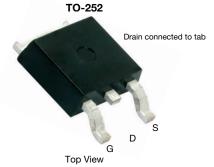
Vishay Siliconix

RoHS

COMPLIANT HALOGEN

FREE

P-Channel 60 V (D-S) MOSFET



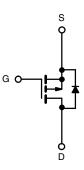
PRODUCT SUMMARY			
V _{DS} (V)	-60		
$R_{DS(on)}$ max. (Ω) at V_{GS} = -10 V	0.015		
$R_{DS(on)}$ max. (Ω) at V_{GS} = -4.5 V	0.020		
I _D (A) ^d	-50		
Configuration	Single		

FEATURES

- TrenchFET[®] power MOSFET
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

· Load switch



P-Channel MOSFET

ORDERING INFORMATION		
Package	TO-252	
Lead (Pb)-free and halogen-free	SUD50P06-15-GE3	
Lead (FD)-free and halogen-free	SUD50P06-15-T4-GE3	

ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted)					
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V _{DS}	-60	V	
Gate-source voltage		V _{GS}	± 20	V	
Continuous drain current (T _J = 175 °C)	T _C = 25 °C		-50 ^d		
	T _C = 125 °C		-27.5		
Pulsed drain current		I _{DM}	-80	A	
Avalanche current		I _{AS}	-50		
Single pulse avalanche energy ^a	L = 0.1 mH	E _{AS}	125	mJ	
Power dissipation	T _C = 25 °C	D	113 °	14/	
	T _A = 25 °C	P _D	2.5 ^{b, c}		
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +150	°C	

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	TYPICAL	MAXIMUM	UNIT
lunation to eaching b	t ≤ 10 s	R _{thJA}	15	18	°C/W
Junction-to-ambient ^b	Steady state		40	50	
Junction-to-case		R _{thJC}	0.82	1.1	

Notes

a. Duty cycle $\leq 1\%$

b. When mounted on 1" square PCB (FR4 material)

c. See SOA curve for voltage derating

d. Package limited

S19-0387 Rev. D, 29-Apr-2019

1





PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static				•		
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0 \text{ V}, \text{ I}_{D} = -250 \mu\text{A}$	-60	-	-	V
Gate threshold voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = -250 \ \mu A$	-1	-	-3	v
Gate-body leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$	-	-	± 100	nA
		$V_{DS} = -60 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	-	-	-1	
Zero gate voltage drain current	I _{DSS}	V_{DS} = -60 V, V_{GS} = 0 V, T_{J} = 125 °C	-	-	-50	μA
		V_{DS} = -60 V, V_{GS} = 0 V, T_{J} = 150 °C	-	-	-100	1
On-state drain current ^a	I _{D(on)}	$V_{DS} = -5 V, V_{GS} = -10 V$	-50	-	-	А
		$V_{GS} = -10 \text{ V}, \text{ I}_{D} = -17 \text{ A}$	-	0.012	0.015	
Drain-source on-state resistance ^a	В	V_{GS} = -10 V, I_D = -50 A, T_J = 125 °C	-	-	0.025	Ω
Drain-source on-state resistance ~	R _{DS(on)}	V_{GS} = -10 V, I_D = -50 A, T_J = 150 °C	-	-	0.028	
		$V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -14 \text{ A}$	-	-	0.020	
Forward transconductance ^a	g fs	$V_{DS} = -15 \text{ V}, \text{ I}_{D} = -17 \text{ A}$	-	61	-	S
Dynamic ^b						
Input capacitance	C _{iss}		-	4950	-	pF
Output capacitance	Coss	V_{GS} = 0 V, V_{DS} = -25 V, f = 1 MHz	-	480	-	
Reverse transfer capacitance	C _{rss}		-	405	-	
Total gate charge ^c	Qg		-	110	165	
Gate-source charge ^c	Q _{gs}	V_{DS} = -30 V, V_{GS} = -10 V, I_{D} = -50 A	-	19	-	nC
Gate-drain charge ^c	Q _{gd}		-	28	-	
Turn-on delay time ^c	t _{d(on)}		-	15	23	
Rise time ^c	t _r	V_{DD} = -30 V, R_L = 0.6 Ω	-	70	105	200
Turn-off delay time ^c	t _{d(off)}	$I_D\cong$ -50 A, V_{GEN} = -10 V, R_G = 6 Ω	-	175	260	ns
Fall time ^c	t _f		-	175	260	
Source-Drain Diode Ratings and Ch	aracteristics	$T_{\rm C} = 25 {}^{\circ}{\rm C} {}^{\rm b}$				
Continuous current	I _S		-	-	-50	А
Pulsed current	I _{SM}		-	-	-80	~
Forward voltage ^a	V _{SD}	$I_F = -50 \text{ A}, \text{ V}_{GS} = 0 \text{ V}$	-	-1	-1.6	V
Reverse recovery time	t _{rr}	I _F = -50 A, di/dt = 100 A/μs	-	45	70	ns

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

b. Guaranteed by design, not subject to production testing

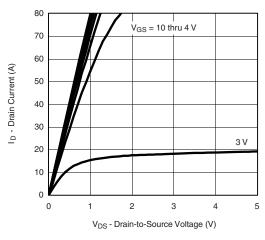
c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

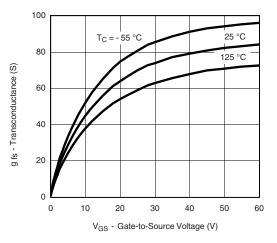
2



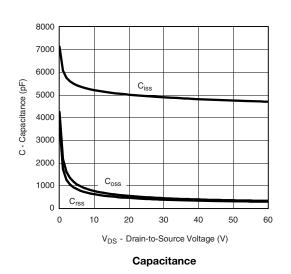
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

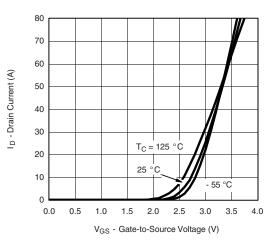


Output Characteristics

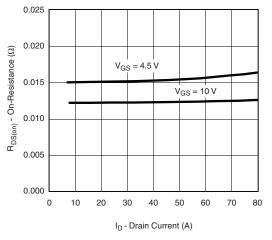


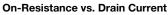


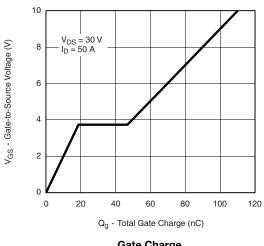




Transfer Characteristics







Gate Charge

S19-0387 Rev. D, 29-Apr-2019

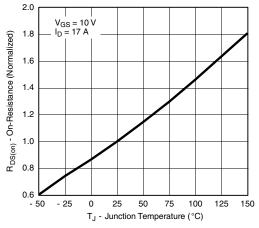
3

For technical questions, contact: pmostechsupport@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u> 10

SUD50P06-15

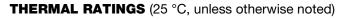
Vishay Siliconix

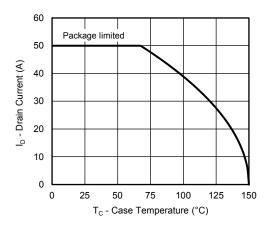
TYPICAL CHARACTERISTICS



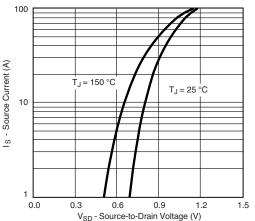
www.vishay.com

On-Resistance vs. Junction Temperature

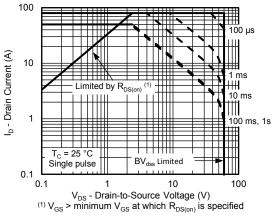




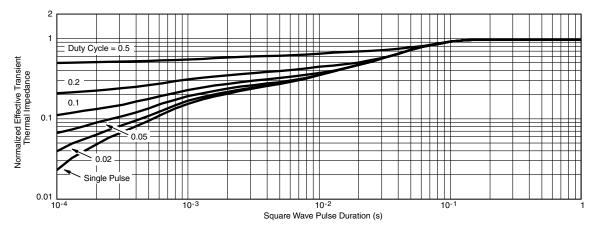
Drain Current vs. Case Temperature



Source-Drain Diode Forward Voltage



Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for silicon technology and package reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?68940.

S19-0387 Rev. D, 29-Apr-201	19
-----------------------------	----

4

For technical questions, contact: <u>pmostechsupport@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>





TO-252AA Case Outline

VERSION 1: FACILITY CODE = Y







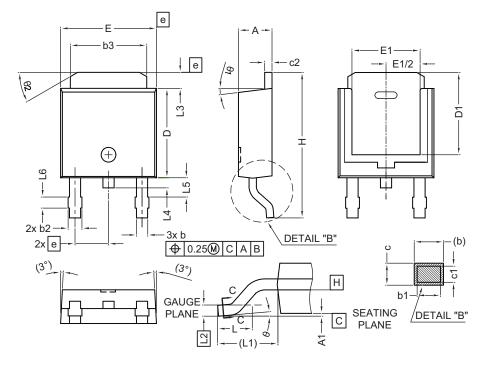
	MILLIMETERS		
DIM.	MIN.	MAX.	
А	2.18	2.38	
A1	-	0.127	
b	0.64	0.88	
b2	0.76	1.14	
b3	4.95	5.46	
С	0.46	0.61	
C2	0.46	0.89	
D	5.97	6.22	
D1	4.10	-	
E	6.35	6.73	
E1	4.32	-	
Н	9.40	10.41	
е	2.28 BSC		
e1	4.56 BSC		
L	1.40	1.78	
L3	0.89	1.27	
L4	-	1.02	
L5	1.01	1.52	

Note

• Dimension L3 is for reference only



VERSION 2: FACILITY CODE = N



	MILLIMETERS		
DIM.	MIN.	MAX.	
A	2.18	2.39	
A1	-	0.13	
b	0.65	0.89	
b1	0.64	0.79	
b2	0.76	1.13	
b3	4.95	5.46	
С	0.46	0.61	
c1	0.41	0.56	
c2	0.46	0.60	
D	5.97	6.22	
D1	5.21	-	
E	6.35	6.73	
E1	4.32	-	
e	2.29 BSC		
Н	9.94	10.34	

	MILLIMETERS		
DIM.	MIN.	MAX.	
L	1.50	1.78	
L1	2.74	ref.	
L2	0.51	BSC	
L3	0.89	1.27	
L4	-	1.02	
L5	1.14	1.49	
L6	0.65	0.85	
θ	0°	10°	
θ1	0°	15°	
θ2	25°	35°	

Notes

• Dimensioning and tolerance confirm to ASME Y14.5M-1994

• All dimensions are in millimeters. Angles are in degrees

• Heat sink side flash is max. 0.8 mm

Radius on terminal is optional

ECN: E19-0649-Rev. Q, 16-Dec-2019 DWG: 5347



RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads Dimensions in Inches/(mm)

Return to Index



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for MOSFET category:

Click to view products by Vishay manufacturer:

Other Similar products are found below :

614233C 648584F IRFD120 JANTX2N5237 2N7000 FCA20N60_F109 FDZ595PZ 2SK2545(Q,T) 405094E 423220D TPCC8103,L1Q(CM MIC4420CM-TR VN1206L 614234A 715780A NTNS3166NZT5G SSM6J414TU,LF(T 751625C IPS70R2K0CEAKMA1 BUK954R8-60E DMN3404LQ-7 NTE6400 SQJ402EP-T1-GE3 2SK2614(TE16L1,Q) 2N7002KW-FAI DMN1017UCP3-7 EFC2J004NUZTDG ECH8691-TL-W FCAB21350L1 P85W28HP2F-7071 DMN1053UCP4-7 NTE221 NTE2384 NTE2903 NTE2941 NTE2945 NTE2946 NTE2960 NTE2967 NTE2969 NTE2976 NTE455 NTE6400A NTE2910 NTE2916 NTE2956 NTE2911 TK10A80W,S4X(S SSM6P69NU,LF DMP22D4UFO-7B